## MSKSEMI















**ESD** 

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# Broduct data sheet







SOT-323

1. BASE

2. EMITTER

3. COLLECTOR

## S9014W

TRANSISTOR (NPN)

#### **FEATURES**

- Complementary to S9015W
- Small Surface Mount Package

#### MAXIMUM RATINGS (T<sub>a</sub>=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	50	V
V <sub>CEO</sub>	Collector-Emitter Voltage	45	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ic	Collector Current	100	mA
Pc	Collector Power Dissipation	200	mW
R <sub>OJA</sub>	Thermal Resistance From Junction To Ambient	625	°C/W
T <sub>J</sub> ,T <sub>stg</sub>	Operation Junction and Storage Temperature Range $^{-55}\sim$		℃

#### ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless otherwise specified)

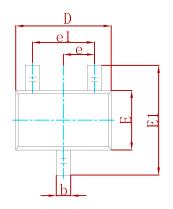
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	I <sub>C</sub> =100μA, I <sub>E</sub> =0	50			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	I <sub>C</sub> =100μA, I <sub>B</sub> =0	45			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I <sub>E</sub> =100μA, I <sub>C</sub> =0	5			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =50V, I <sub>E</sub> =0			100	nA
Collector cut-off current	I <sub>CEO</sub>	V <sub>CE</sub> =35V, I <sub>B</sub> =0			1	uA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =4V, I <sub>C</sub> =0			100	nA
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =1mA	200		1000	
Collector-emitter saturation voltage	$V_{CE(sat)}$	I <sub>C</sub> =100mA, I <sub>B</sub> =5mA			0.3	V
Base-emitter saturation voltage	$V_{BE(sat)}$	I <sub>C</sub> =100mA, I <sub>B</sub> =5mA			1	V
Base-emitter voltage	$V_{BE}$	V <sub>CE</sub> =5V, I <sub>C</sub> =2mA	0.58		0.7	V
Transition frequency	f⊤	V <sub>CE</sub> =5V,I <sub>C</sub> =10mA, f=30MHz	150			MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz			3.5	pF

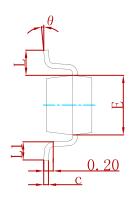
#### **CLASSIFICATION OF h**<sub>FE</sub>

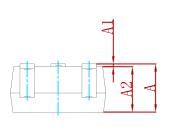
RANK	L	Н
RANGE	200 - 450	450 - 1000
MARKING	J6	



#### **PACKAGE MECHANICAL DATA**

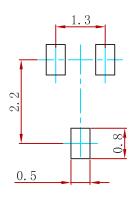






Cumbal	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.200	0.400	0.008	0.016	
С	0.080	0.150	0.003	0.006	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.650	) TYP	0.026	6 TYP	
e1	1.200	1.400	0.047	0.055	
L	0.525 REF		0.02	I REF	
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

## Suggested Pad Layout



#### Note:

- 1. Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

#### **REEL SPECIFICATION**

P/N	PKG	QTY
S9014W	SOT-323	3000



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